IN THE SPECIFICATION

Please amend the paragraph beginning at page 27, line 20, as follows:

FIG. 8(A) shows a modification of the first embodiment. The side face of each of the conductive layers 34P, 34E of the core substrate 30 is in the form of taper (linear taper shown in FIG. 10(B) FIG. 8(B) or rounded taper shown in FIG. 10(C) FIG. 8(C)). When an angle formed by a straight line connecting the top end and the bottom end of the side face of the conductive layers 34P, 34E and a horizontal face of the core substrate is assumed to be Θ or when an angle formed by a straight line connecting the top end and bottom end of the side face of the conductive layers 34P, 34E in the inner layer of the core substrate and the core substrate is assumed to be Θ , the Θ satisfies the relational expression of 2.8<tan Θ <55.